

Data collection

Nonius CAD-4 diffractometer	$R_{\text{int}} = 0.052$
$\omega/2\theta$ scans	$\theta_{\text{max}} = 35^\circ$
Absorption correction:	$h = -16 \rightarrow 16$
ψ scan (North <i>et al.</i> , 1968)	$k = 0 \rightarrow 14$
$T_{\text{min}} = 0.494$, $T_{\text{max}} = 0.667$	$l = -11 \rightarrow 11$
2928 measured reflections	3 standard reflections
1469 independent reflections	frequency: 120 min
	intensity decay: 2.0%

Refinement

Refinement on F^2	$\Delta\rho_{\text{max}} = 2.168 \text{ e } \text{\AA}^{-3}$
$R[F^2 > 2\sigma(F^2)] = 0.037$	(at 0.62 \AA from Mo2)
$wR(F^2) = 0.095$	$\Delta\rho_{\text{min}} = -1.759 \text{ e } \text{\AA}^{-3}$
$S = 1.135$	(at 0.66 \AA from Mo1)
1469 reflections	Extinction correction:
65 parameters	<i>SHELXL93</i> (Sheldrick, 1993)
$w = 1/[\sigma^2(F_o^2) + (0.0407P)^2 + 2.6794P]$	Extinction coefficient:
where $P = (F_o^2 + 2F_c^2)/3$	0.0006 (3)
$(\Delta/\sigma)_{\text{max}} < 0.001$	Scattering factors from
	<i>International Tables for Crystallography</i> (Vol. C)

Table 1. Fractional atomic coordinates and equivalent isotropic displacement parameters (\AA^2)

$$U_{\text{eq}} = (1/3)\sum_i \sum_j U^{ij} a^i a^j \cdot \mathbf{a}_i \cdot \mathbf{a}_j$$

	x	y	z	U_{eq}
Mo1	0.27128 (5)	0	0.40442 (8)	0.00776 (13)
Mo2	1/2	0.24850 (6)	0	0.00722 (13)
Co1†	1/2	0.32151 (10)	1/2	0.0080 (2)
Fe1‡	1/2	0.32151 (10)	1/2	0.0080 (2)
Co2§	0.19949 (9)	0	-0.14440 (13)	0.0077 (2)
Fe2¶	0.19949 (9)	0	-0.14440 (13)	0.0077 (2)
O1	0.3662 (4)	0.1562 (5)	0.4720 (7)	0.0234 (8)
O2	0.1415 (5)	0	0.5393 (7)	0.0090 (8)
O3	0.4576 (3)	0.3472 (4)	0.1959 (5)	0.0109 (6)
O4	0.3577 (4)	0.1440 (4)	-0.1093 (6)	0.0187 (7)
O5	0.2016 (6)	0	0.1458 (8)	0.0230 (13)

† Site occupancy = 0.57 (9). ‡ Site occupancy = 0.43 (9). § Site occupancy = 0.82 (9). ¶ Site occupancy = 0.18 (9).

Table 2. Selected bond lengths (\AA)

Mo1—O1	1.731 (4)	Co1—O3 ⁱⁱⁱ	2.066 (3)
Mo1—O1 ⁱ	1.731 (4)	Co1—O3	2.066 (3)
Mo1—O5	1.748 (6)	Co1—O2 ^b	2.163 (3)
Mo1—O2	1.841 (5)	Co1—O2 ^c	2.163 (3)
Mo2—O4	1.731 (4)	Co2—O5	2.032 (6)
Mo2—O4 ⁱⁱ	1.731 (4)	Co2—O4	2.057 (4)
Mo2—O3	1.807 (3)	Co2—O4 ⁱ	2.057 (4)
Mo2—O3 ⁱⁱ	1.807 (3)	Co2—O3 ^{vi}	2.093 (4)
Co1—O1	2.026 (4)	Co2—O3 ^{vii}	2.093 (4)
Co1—O1 ⁱⁱⁱ	2.026 (4)	Co2—O2 ^{viii}	2.126 (5)

Symmetry codes: (i) $x, -y, z$; (ii) $1 - x, y, -z$; (iii) $1 - x, y, 1 - z$; (iv) $\frac{1}{2} + x, \frac{1}{2} + y, z$; (v) $\frac{1}{2} - x, \frac{1}{2} - y, 1 - z$; (vi) $\frac{1}{2} - x, y - \frac{1}{2}, -z$; (vii) $\frac{1}{2} - x, \frac{1}{2} - y, -z$; (viii) $x, y, z - 1$.

The occupancy factors for Co and Fe were refined as least-squares parameters with the sum for each site constrained to be 1, but without constraints for the overall Co:Fe ratio.

Data collection: *CAD-4 Diffractometer Control Software* (Nonius, 1993). Cell refinement: *CAD-4 Diffractometer Control Software*. Data reduction: *X-RED* (Stoe & Cie, 1996). Program(s) used to solve structure: *SHELXS86* (Sheldrick, 1990).

Program(s) used to refine structure: *SHELXL93* (Sheldrick, 1993). Software used to prepare material for publication: *SHELXL93*.

Financial support from the Deutsche Forschungsgemeinschaft (grant No. WE1542/3-2) is gratefully acknowledged.

Supplementary data for this paper are available from the IUCr electronic archives (Reference: BR1241). Services for accessing these data are described at the back of the journal.

References

- Abrahams, S. C. & Reddy, J. M. (1965). *J. Chem. Phys.* **43**, 2533–2543.
- Ehrenberg, H., Wltschek, G., Trouw, F., Kroener, T., Weitzel, H. & Fuess, H. (1994). *J. Magn. Magn. Mater.* **135**, 355–360.
- Nonius (1993). *CAD-4 Diffractometer Control Software*. Nonius GmbH, Solingen, Germany.
- North, A. C. T., Phillips, D. C. & Mathews, F. S. (1968). *Acta Cryst.* **A24**, 351–359.
- Sheldrick, G. M. (1990). *Acta Cryst.* **A46**, 467–473.
- Sheldrick, G. M. (1993). *SHELXL93. Program for the Refinement of Crystal Structures*. University of Göttingen, Germany.
- Sleight, A. W. & Chamberland, B. L. (1968). *Inorg. Chem.* **7**, 1672–1675.
- Stoe & Cie (1996). *X-RED. Data Reduction Program*. Stoe & Cie, Darmstadt, Germany.

Acta Cryst. (1999). **C55**, 1384–1388

Potassium β'' -aluminogallate

KRISTINA EDSTRÖM

Inorganic Chemistry, The Ångström Laboratory, Uppsala University, Box 538, SE-751 21 Uppsala, Sweden. E-mail: kristina.edstrom@kemi.uu.se

(Received 13 November 1998; accepted 7 June 1999)

Abstract

The single-crystal structure of a non-stoichiometric potassium β'' -aluminogallate, $\text{K}_{1.67}\text{Mg}_{0.67}\text{Al}_{8.58}\text{Ga}_{1.75}\text{O}_{17}$, has been determined by X-ray diffraction. The Ga atoms were found to occupy predominantly a tetrahedral 6c site (space group $R\bar{3}m$) in the middle of a spinel block of aluminium oxide with a site occupation of 51.6%. All the charge-stabilizing Mg^{2+} ions are found in the same site. Ga atoms are also found with a site occupation of 12.7% in the other tetrahedral 6c site, a site occupation of 7.6% in an octahedral 18h site and a site occupation of 0.9% in the second octahedral 3a site. The K^+ ions lie distributed along edge-linked hexagonal pathways with

two maxima, one at a $6c$ site and one at an $18h$ site with an occupation ratio of 69:31.

Comment

Potassium β'' -alumina is well known for its high K^+ ion conductivity (Brown *et al.*, 1981) and can as such be used in many technical applications as a solid electrolyte or sensor. The K^+ ions can easily be exchanged for other positive mono-, di- or trivalent ions by simply immersing a single crystal or a powder of K^+ β'' -alumina in a salt melt at elevated temperatures containing the ion to be exchanged (Kummer, 1972). Thus, good silver, lithium and sodium ionic conductors can be obtained. The present study was performed in order to monitor the effect that changing the spinel framework of a β'' -alumina has on the mobile ion properties and to facilitate ion-exchange possibilities. By exchanging some of the Al atoms in β'' -alumina for Ga atoms and thus creating a β'' -aluminogallate structure, new insight into subtle structural details of charge compensation and transport mechanisms in these non-stoichiometric materials can be obtained (Aka *et al.*, 1990).

The title structure can be described as trigonal with spinel blocks of aluminium oxide interleaved by conduction planes containing the K^+ ions (Fig. 1). There are four crystallographically independent Al sites in

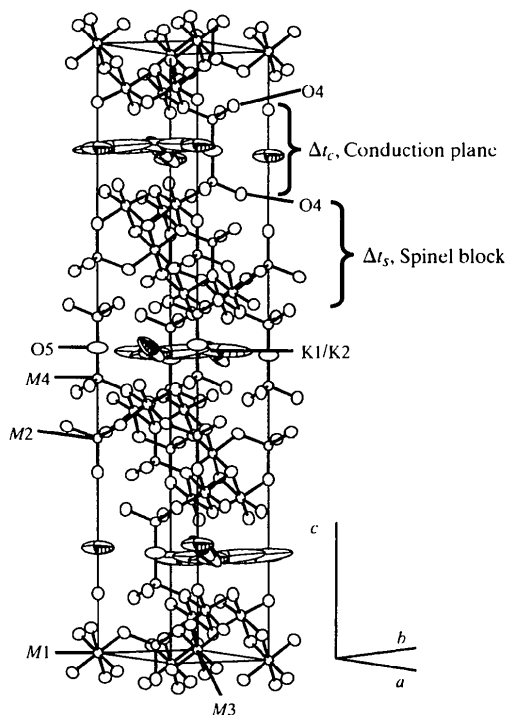


Fig. 1. The structure of K^+ β'' -aluminogallate. Atoms are drawn to include 99% probability.

the spinel block that can be exchanged for Ga atoms, *i.e.* two octahedral sites and two tetrahedral sites. The structure is charge-stabilized by Mg^{2+} ions at tetrahedral $6c$ positions in the middle of the spinel block. The K^+ ion mobility occurs in two-dimensional honeycomb pathways around the column O5 atom in the conduction plane.

The results of this study show that the Ga atoms preferentially occupy the same tetrahedral $6c$ site ($M2$) in the middle of the spinel block as the charge-stabilizing Mg^{2+} ions (Fig. 1 and Table 1). The other three sites are also partially substituted by Ga atoms, but the exchange pattern is quite complex. It is not as simple as just assuming that the Ga atoms prefer the tetrahedral sites to the octahedral sites compared with Al atoms, as suggested earlier (Aka *et al.*, 1990). By comparing the results obtained here with those from an earlier study on a series of Na^+ β'' -aluminogallate crystals with different gallium substitutions (Edström *et al.*, 1998), a clearer picture of the substitution pattern emerges (Fig. 2). As can be seen in Fig. 2, the first site in the spinel block to exchange for Ga atoms is the $M2$ site (a tetrahedral $6c$ site). The second most substituted aluminium site is the tetrahedral $M4$ site (also crystallographically a $6c$ site). The third $M3$ site to be substituted is the octahedral $18h$ site. The most difficult site to substitute is $M1$, the second octahedral $3a$ site. The substitution pattern, however, is similar in all these three exchanged sites in all the aluminogallates examined (Fig. 2). After the $M2$ site has been completely filled with 67% gallium (the remainder, 33%, is magnesium, see Fig. 2) at 30% total gallium substitution, all the other three sites are substituted at an equal rate. The electronic structure of gallium offers an explanation of the nature

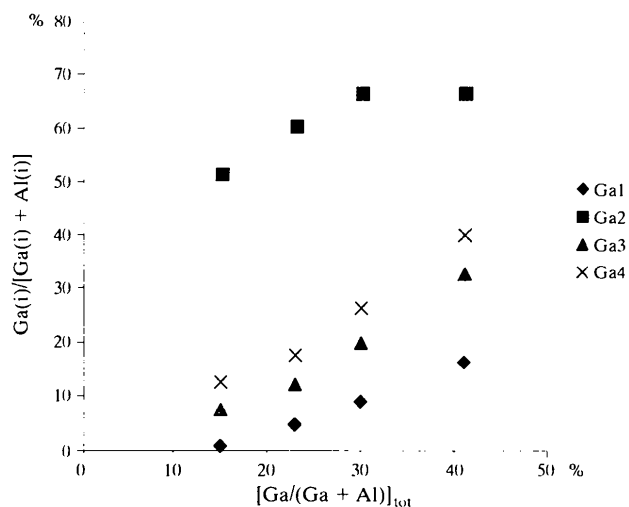


Fig. 2. The gallium content of each metal atom site-type (y axis) for each composition (x axis) of 15% Ga in K^+ β'' -aluminogallate, and 23, 30 and 41% Ga in Na^+ β'' -aluminogallate (Edström *et al.*, 1998).

of site occupation in β'' -aluminogallates. Aluminium and gallium have similar chemical reactivities, one difference being that gallium has a filled d shell, giving it a tendency to form covalent bonds using sp^3 hybrid orbitals. This can explain the tendency for gallium to prefer a tetrahedral coordination compared with aluminium and hence replace the tetrahedral aluminium more readily than the aluminium at the octahedral sites, though the replacement pattern as demonstrated in this study seems to be more subtle than earlier believed (Taufelle *et al.*, 1993).

Earlier studies performed on the substitution of aluminium by gallium in polycrystalline β -alumina (Brinkhoff, 1974) show that the unit-cell parameters increase linearly with gallium content, but this increase did not change the Na^+ ion conductivity. K^+ ion conductivity, on the other hand, decreased with increasing gallium content. The first report regarding the existence of a β'' -aluminogallate phase was presented by Aka *et al.* (1990). Here also an increase in unit-cell parameters with increasing gallium substitution was reported. One of the considerations here was to determine whether the increase in the c -axis parameter influences transport properties and gives an increase in width of the conduction plane. From a knowledge of the thickness of the spinel block, Δt_s (Fig. 1), defined as the distance between the planes that are parallel to the conduction plane and which contain the O4 atoms, and the thickness of the conduction slab, $\Delta t_c = \frac{1}{3}(c - 3\Delta t_s)$, a determination of the increase in conduction plane width can be assessed with increasing gallium substitution (Michiue *et al.*, 1989; Iyi *et al.*, 1986). In the study of Na^+ β'' -aluminogallate, it could be shown how the increase in the c -axis parameter had a relatively small effect on the thickness of the conduction slab (Edström *et al.*, 1998). From this result, it was not surprising that conductivity values for 30 and 41% total gallium substitution are virtually identical to those of Na^+ β'' -alumina (Faltens & Dunn, 1993). In comparison, the calculated thickness of the spinel block and conduction slabs are 6.70 and 4.66 Å for K^+ β'' -alumina [calculation based on data from Brown *et al.* (1981)], and 6.679 (1) and 4.728 (1) Å for the K^+ β'' -aluminogallate reported here. These values can be compared with values of 6.80 and 4.70 Å in K^+ β'' -gallate (Michiue *et al.*, 1989). The small increase in the c -axis parameter has relatively little effect on the thickness of the conduction slab.

The K^+ ion distribution is so spatially extended that the refined models are to some extent inadequate. Large correlations exist between the positional, occupational and displacement parameters of the K^+ ions. The best model found to describe the distribution is one in which all the K^+ ions are found in two sites, namely a $6c$ site with the distribution best described by β_{ij} - and γ_{ijk} tensors, and an $18h$ site described by β_{ij} tensors (Figs. 3 and 4). Generally, however, the refined K^+ ion distribution is similar to that reported for K^+ β'' -alumina

(Bettman & Peters, 1969; Iyi *et al.*, 1986; Brown *et al.*, 1981) and K^+ β'' -gallate (Michiue *et al.*, 1989). Partial occupation of gallium in the spinel block seems to influence the K^+ ion distribution in the conduction plane, resulting in the broader ion distribution reported for K^+ β'' -alumina (Brown *et al.*, 1981). The displacement parameter for O5 is unusually high (Table 1), which has also been seen to be the case at temperatures as low as 30 K (Edström *et al.*, 1997). Molecular dynamics simulations (Thomas & Zendejas, 1989) have shown an influence of the mobile ion on the O5 atoms in Na^+ β'' -alumina. The high displacement parameter would thus be a sign of a positional disorder. The extended electron density for the K^+ ions combined with the unusually high displacement parameter of the O5 atom in the conduction plane is consistent with the ionic conductivity reported for K^+ β'' -aluminogallate and the good ion-exchange property observed for this compound (Faltens & Dunn, 1993).

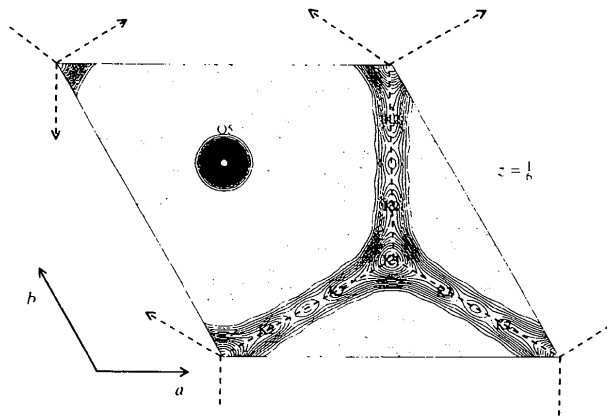


Fig. 3. Final F_{obs} synthesis for K^+ β'' -aluminogallate at $z = \frac{1}{6}$. Contour intervals are $1.0 e \text{ \AA}^{-3}$.

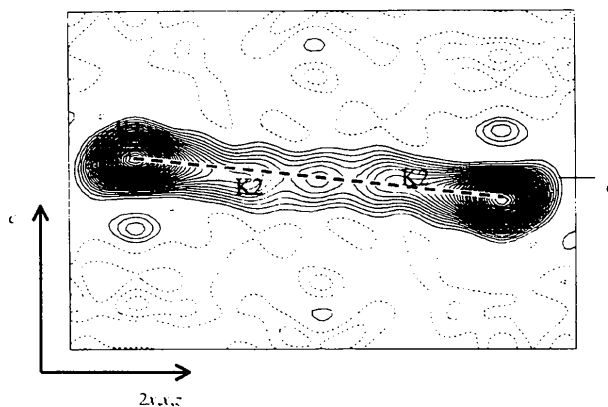


Fig. 4. Observed Fourier synthesis perpendicular to the conduction path. Contour intervals are $1.0 e \text{ \AA}^{-3}$.

Experimental

Single crystals of Na⁺ β''-aluminogallate were grown by the flux-evaporation technique using Na₂CO₃ fluxes (Aka *et al.*, 1990). The starting compounds were Al₂O₃, Ga₂O₃, Na₂CO₃, NaF and MgO. The crystal was grown in air at 1798 K over a period of 10 d. The resulting crystals were of good size (5 × 5 × 1 mm) and quality. The composition of Na⁺ β''-aluminogallate was then determined by atomic absorption analysis with the element content (in moles): Na 1.66 (1), Mg 0.66 (1), Al 8.53 (1) and Ga 1.87 (1) (Aka *et al.*, 1990). The Na⁺ ions were then ion-exchanged for K⁺ ions in a stepwise manner in a series of mixed KNO₃/NaNO₃ salts containing 10, 50 and 100% KNO₃ at 623 K. The crystal was soaked for several hours during each step, and also washed and weighed between steps to monitor the exchange. To have an estimate of the crystal content after the ionic exchange, the experimental linear absorption coefficient was measured as 5.1 (1) mm⁻¹ (which is in agreement with the calculated value of 5.023 mm⁻¹). From the fully exchanged crystal, which was found to be hygroscopic, was cut a piece suitable for X-ray diffraction. Prior to the X-ray investigation, the crystal was heat treated at 575 K to get rid of any water present. The crystal was then mounted in a glass capillary to prevent water uptake.

Crystal data

K_{1.67}Mg_{0.67}Al_{8.58}Ga_{1.75}O₁₇

M_r = 699.39

Trigonal

*R*3̄*m*

a = 5.6665 (2) Å

c = 34.2196 (17) Å

V = 951.56 (7) Å³

Z = 3

D_x = 3.6972 Mg m⁻³

D_m not measured

Data collection

Stoe diffractometer

θ/2θ scans

Absorption correction:

by integration (explicit

crystal size and shape)

T_{min} = 0.670, *T_{max}* = 0.769

3571 measured reflections

3571 independent reflections

(1267 reflections after

merging)

Refinement

Refinement on *F*²

R(*F*) = 0.018

wR(*F*²) = 0.062

S = 1.81

3375 reflections

54 parameters

w = 1/[σ²(*F*) + 0.02*F*²]

(Δ/σ)_{max} = 0.100

Δρ_{max} = 0.73 e Å⁻³

Δρ_{min} = -1.19 e Å⁻³

Mo *K*α radiation

λ = 0.71073 Å

Cell parameters from 30

reflections

θ = 25–30°

μ = 4.661 mm⁻¹

T = 293 K

Triangular

0.13 × 0.11 × 0.05 mm

Colourless

3375 reflections with

I_{net} > 2σ(*I_{net}*)

R_{int} = 0.025

θ_{max} = 50°

h = -5 → 10

k = -5 → 10

l = -73 → 73

5 standard reflections

frequency: 180 min

intensity decay: 1.2%

Extinction correction: Becker & Coppens (1974), isotropic (type 1)

Extinction coefficient:

1.613 × 10⁵

Scattering factors from *International Tables for X-ray Crystallography* (Vol. IV)

Table 1. Fractional atomic coordinates and equivalent isotropic displacement parameters (Å²)

		$U_{eq} = (1/3)\sum_i \sum_j U^{ij} a^i a^j \mathbf{a}_i \cdot \mathbf{a}_j$				<i>U_{eq}</i>
	Occupancy	<i>x</i>	<i>y</i>	<i>z</i>		
K1	0.36 (1)	6c	0	0	0.17131 (7)	0.0390 (3)
K2	0.16 (1)	18h	0.173 (2)	0.0863 (11)	0.16808 (5)	0.113 (8)
Mg	0.1111	6c	0	0	0.34985 (1)	0.00380 (5)
Ga1	0.00895 (6)	3a	0	0	0	0.00409 (14)
Al1	0.99105 (6)	3a	0	0	0	0.00409 (14)
Ga2	0.5162 (1)	6c	0	0	0.349850 (4)	0.00380 (5)
Al2	0.1505 (1)	6c	0	0	0.349850 (4)	0.00380 (5)
Ga3	0.0763 (2)	18h	0.33381 (2)	0.16690 (1)	0.070602 (4)	0.00471 (6)
Al3	0.9237 (2)	18h	0.33381 (2)	0.16690 (1)	0.070602 (4)	0.00471 (6)
Ga4	0.1266 (1)	6cc	0	0	0.44921 (1)	0.00470 (6)
Al4	0.8734 (1)	6c	0	0	0.44921 (1)	0.00470 (6)
O1	1	18h	0.15171 (3)	0.30343 (6)	0.03426 (1)	0.00704 (12)
O2	1	6c	0	0	0.29440 (2)	0.00673 (10)
O3	1	6c	0	0	0.09591 (2)	0.00655 (15)
O4	1	18h	0.16374 (3)	0.32748 (5)	0.23574 (1)	0.00692 (12)
O5	1	3b	1/3	2/3	1/6	0.0150 (3)

Table 2. Selected distances (Å)

K1—O3	2.580 (3)	Mg—O1	1.8831 (3)
K1—O4	2.728 (2)	Mg—O2	1.8975 (6)
K1—O4	2.728 (2)	Al3—O1	2.0020 (3)
K1—O4	2.728 (2)	Al3—O1	2.0020 (3)
Ga1—O1	1.8951 (3)	Al3—O2	1.9602 (3)
Ga1—O1	1.8951 (3)	Al3—O3	1.8530 (3)
Ga1—O1	1.8951 (3)	Al3—O4	1.8651 (2)
Ga1—O1	1.8951 (3)	Al3—O4	1.8651 (2)
Ga1—O1	1.8951 (3)	Al4—O4	1.7782 (3)
Ga1—O1	1.8951 (3)	Al4—O4	1.7782 (3)
Ga2—O1	1.8831 (3)	Al4—O4	1.7782 (3)
Ga2—O1	1.8831 (3)	Al4—O5	1.7380 (2)
Ga2—O1	1.8831 (3)	Al1—O1	1.8951 (3)
Ga2—O2	1.8975 (6)	Al1—O1	1.8951 (3)
Ga3—O1	2.0020 (3)	Al1—O1	1.8951 (3)
Ga3—O1	2.0020 (3)	Al1—O1	1.8951 (3)
Ga3—O2	1.9602 (3)	Al1—O1	1.8951 (3)
Ga3—O3	1.8530 (3)	Al1—O1	1.8951 (3)
Ga3—O4	1.8651 (2)	Al2—O1	1.8831 (3)
Ga3—O4	1.8651 (2)	Al2—O1	1.8831 (3)
Ga4—O4	1.7782 (3)	Al2—O1	1.8831 (3)
Ga4—O4	1.7782 (3)	Al2—O2	1.8975 (6)
Ga4—O4	1.7782 (3)	K2—K1	2.43 (1)
Ga4—O5	1.7380 (2)	K2—O3	2.611 (4)
Mg—O1	1.8831 (3)	K2—O4	2.702 (2)
Mg—O1	1.8831 (3)	K2—O4	2.702 (2)

The intensity measurements were corrected for background (Lehman & Larsen, 1974), and the standard reflections were used to scale intensities and s.u.'s (McCandlish *et al.*, 1975). Refinements were carried out using a PC version of the full-matrix least-squares program *DUPALS* (Lundgren, 1982). All refinements were based on an unmerged data set. The reason for this is mainly to avoid merging reflections which are uncorrected for extinction. Anomalous dispersion terms and coherent scattering amplitudes used for Al³⁺, O²⁻, Mg²⁺, Ga³⁺ and K⁺ were those taken from *International Tables for X-ray Crystallography* (Vol. IV, 1974). The structure was refined in the *R*3̄*m* space group. A scale factor was first refined using the structural parameters taken from Na⁺ β''-alumina (Bettman & Peters, 1969). The occupation of the Mg atoms at site Mg2 (Table 1) was kept constant during the refinement. This assumption was based on chemical analysis by atomic absorption spectroscopy (Aka *et al.*, 1990) and neutron diffraction studies of Na⁺ β''-alumina (Fraser *et al.*, 1983), where it has been shown that magnesium only occupies one site in the structure, a tetrahedral 6c site. The Ga atoms in the spinel block could then be located in a difference

Fourier synthesis. A negative peak was found at the *M2* site, indicating that too much electron density was present in this site to model the structure. This peak suggests either more Mg atoms in this site or some Al atoms still remaining. The chosen model assumed the latter (Table 1). The K⁺ ion distribution was then determined. The K1 ion was refined in a 6*c* site described with β_{ij} displacement parameters: $\beta_{11} = \beta_{22} = 2\beta_{12} = 0.0402$ (5) and $\beta_{33} = 0.000126$ (5), and third-order cumulant displacement parameters, γ_{ijk} : $\gamma_{111} = -\gamma_{222} = 2\gamma_{112} = -2\gamma_{122} = 0.018$ (1), $\gamma_{333} = -0.00003$ (1) and $\gamma_{133} = -\gamma_{233} = 2\gamma_{123} = 0.00054$ (6). An extra K⁺ ion had to be included at an 18*h* site with isotropic displacement parameters. The total number of K⁺ ions was constrained to be 1.67 per formula unit. This constraint was also based on the starting amount of sodium ions as determined by chemical analysis with atomic absorption spectroscopy and the weight-exchange measurements. Refinement tests were carried out on the reliability of the constraints of the occupations for the Mg atoms and the K⁺ ions. The occupations were refined freely but no significant difference from the constrained occupations was noticed. The constraints were then kept in the final refinements to reduce the number of refined parameters.

Data reduction: *STOEDATR* (Lundgren, 1982). Program(s) used to refine structure: *DUPALS* (Lundgren, 1982). Molecular graphics: *ORTEPII* (Johnson, 1976). Software used to prepare material for publication: *DISTAN* (Lundgren, 1982).

This work has been supported by grants from The United States Office of Naval Research (ONR) and The Swedish Natural Science Research Council (NFR). The author would like to thank Professor Josh Thomas (University of Uppsala) for his many useful and inspiring suggestions.

Supplementary data for this paper are available from the IUCr electronic archives (Reference: BR1232). Services for accessing these data are described at the back of the journal.

References

- Aka, G., Dunn B., Foreman, J. & Farrington, G. C. (1990). *Solid State Ionics*, **40/41**, 83–86.
- Becker, P. J. & Coppens, P. (1974). *Acta Cryst.* **A30**, 129–147.
- Bettman, M. & Peters, C. R. (1969). *J. Phys. Chem.* **73**, 1774–1780.
- Brinkhoff, H. C. (1974). *J. Phys. Chem. Solids*, **35**, 1225–1229.
- Brown, G. M., Schwinn, D. A., Bates, J. B. & Brundage, W. E. (1981). *Solid State Ionics*, **5**, 147–150.
- Edström, K., Faltens, T. A. & Dunn, B. (1998). *Solid State Ionics*, **110**, 137–144.
- Edström, K., Thomas, J. O. & Farrington, G. (1997). *Acta Cryst.* **B53**, 631–638.
- Faltens, T. A. & Dunn, B. (1993). *Solid State Ionics*, **66**, 321–329.
- Frase, K. G., Thomas, J. O. & Farrington, G. C. (1983). *Solid State Ionics*, **9/10**, 307–310.
- Iyi, N., Inoue, Z. & Kimura, S. (1986). *J. Solid State Chem.* **61**, 81–89.
- Johnson, C. K. (1976). *ORTEPII*. Report ORNL-5138. Oak Ridge National Laboratory, Tennessee, USA.
- Kummer, J. T. (1972). *Progress in Solid State Chemistry*, Vol. 1, edited by H. Reiss & J. O. McCaldin, pp. 141–175. Oxford: Pergamon.
- Lehman, M. S. & Larsen, F. K. (1974). *Acta Cryst.* **A30**, 580–584.
- Lundgren, J.-O. (1982). *Crystallographic Computer Programs*. Report UUIC-B13-04-05. Institute of Chemistry, University of Uppsala, Sweden.

- McCandlish, L. E., Stout, G. H. & Andrews, L. C. (1975). *Acta Cryst.* **A31**, 245–249.
- Michiue, Y., Watanabe, M. & Fujiki, Y. (1989). *Solid State Ionics*, **35**, 223–227.
- Taulelle, F., Maquet, J., Lucas, V., Thery, J., Kahn-Harari, A., Faltens, T. A. & Dunn, B. (1993). *Appl. Magn. Reson.* **4**, 101–106.
- Thomas, J. O. & Zendejas, M. A. (1989). *J. Comput.-Aided Mol. Des.* **3**, 311–325.

Acta Cryst. (1999). **C55**, 1388–1391

(NH₄)₂[Mg₄(H₂O)₁₈(H₂W₁₂O₄₂)]·10H₂O, a new compound containing chains formed by magnesium and paradodecahedral tungstate ions

JING LI,^a RU-JI WANG^b AND CHARLIE C. TORARDI^c

^aDepartment of Chemistry, Rutgers University, Camden, NJ 08102, USA, ^bAnalysis Center, Tsinghua University, Beijing 100084, People's Republic of China, and ^cCentral Research and Development, DuPont Company, Experimental Station, Wilmington, DE 19880, USA. E-mail: wangrj@sam.chem.tsinghua.edu.cn

(Received 10 February 1999; accepted 5 May 1999)

Abstract

A new ammonium magnesium paradodecatungstate decahydrate, namely diammonium octadecaaquahydrogentetramagnesiodecatungstate decahydrate, (NH₄)₂·[Mg₄(H₂O)₁₈(H₂W₁₂O₄₂)]·10H₂O, was prepared by the reaction of (NH₄)₁₀[H₂W₁₂O₄₂]·4H₂O with MgCl₂ in aqueous solution. The skeleton of the paradodecatungstate ion, [H₂W₁₂O₄₂]¹⁰⁻, is basically the same as those in the known paradodecatungstates. It consists of 12 interconnected WO₆ octahedra and its centre is located at a crystallographic inversion centre. Both independent Mg atoms are octahedrally coordinated by six O atoms. One magnesium octahedron shares an O atom with a paradodecatungstate group and the other magnesium octahedron shares two O atoms, each with different paradodecatungstate groups, to form a one-dimensional [Mg₄(H₂O)₁₈(H₂W₁₂O₄₂)]_n²ⁿ⁻ chain along the *b* direction.

Comment

Many paradodecatungstates have been investigated by X-ray diffraction methods; examples include (NH₄)₁₀[H₂W₁₂O₄₂]·4H₂O (D'Amore & Allman, 1972), Na₁₀[H₂W₁₂O₄₂]·20H₂O (Chrissafidou *et al.*, 1995), K₁₀[H₂W₁₂O₄₂]·7.5H₂O (Evans *et al.*, 1993) and Mg₅·[H₂W₁₂O₄₂]·38H₂O (Tsay & Silverton, 1973). The po-